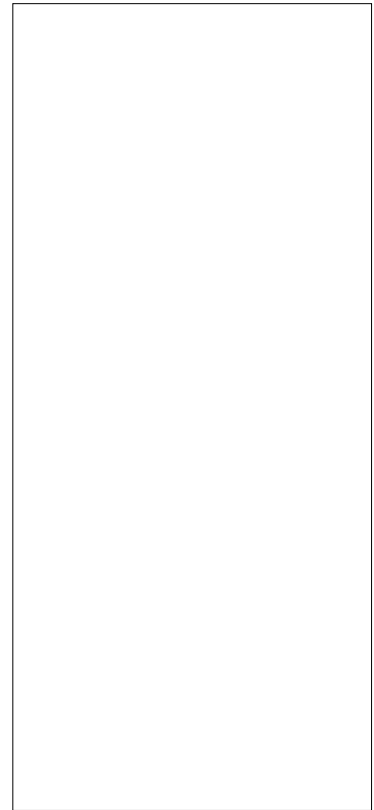




ACJP01U-800SW 1A TRIAC

Rev.A.2.1

The ACJP01U-800SW triac is suitable for general purpose AC switching. It can be used as an ON/OFF function in applications



Average gate power dissipation ($T_j=125$)	$P_{G(AV)}$	0.1	W
Peak gate power	P_{GM}	2	W
Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG.7)	V_{pp}	4.5	kV

(T_j=25 unless otherwise specified)

Symbol	Test Condition	Quadrant	Value		Unit
I _{GT}	V _D =12V R _L =33Ω	-	MAX.	10	mA
V _{GT}		-	MAX.	1	V
V _{GD}	V _D =V _{DRM} T _j =125 R _L =3.3kΩ	-	MIN.	0.15	V
I _L	I _G =1.2I _{GT}		MAX.	25	mA
				10	
I _H	I _T =100mA		MAX.	10	mA
dV/dt	V _D =540V Gate Open T _j =125		MIN.	100	V/μs
(dI/dt) _c	(dV/dt) _c =10V/μs, T _j =125		MIN.	0.6	A/ms
t _{on}	I _G =20mA I _A =200mA I _R =20mA		TYP.	2.5	μs
t _{off}	T _j =25			25	
V _{CL}	I _{CL} =0.1mA t _p =1ms		MIN.	900	V

Symbol	Parameter		Value(MAX.)	Unit
V_{TM}	$I_{TM}=1.1A$ $t_p=380\mu s$	$T_j=25$	1.3	V
V_{TO}	Threshold voltage	$T_j=125$	0.77	V
R_D	Dynamic resistance	$T_j=125$	276	m Ω
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25$	5	μA
I_{RRM}		$T_j=125$	0.4	mA

Symbol	Parameter	Value	Unit
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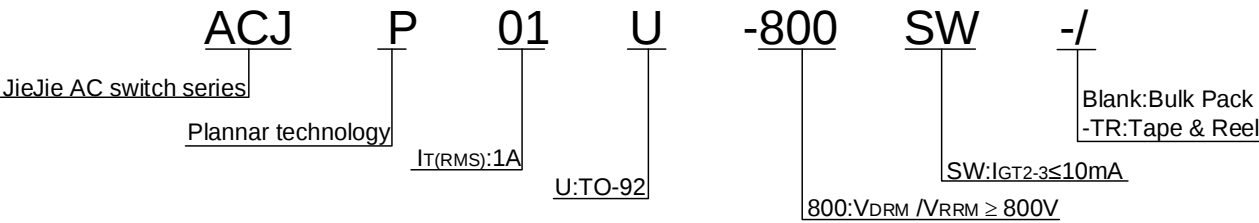


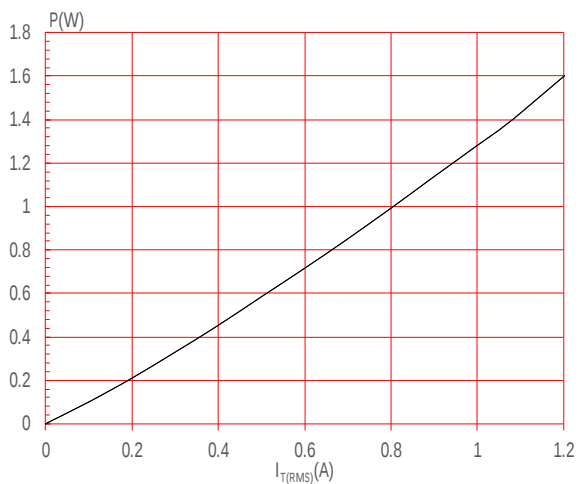
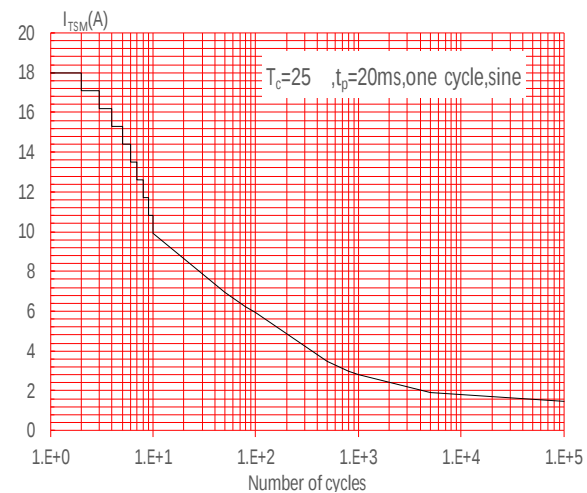
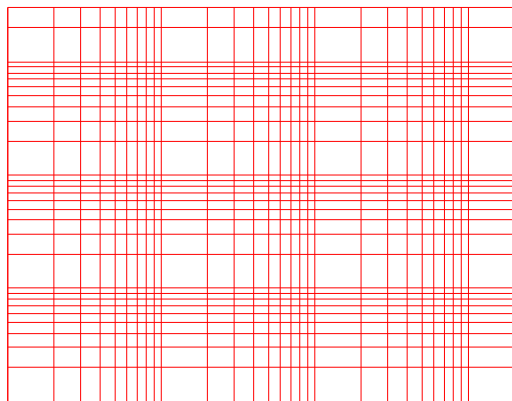
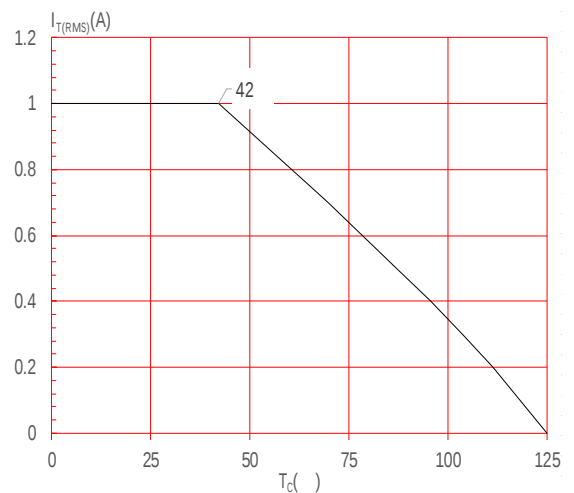
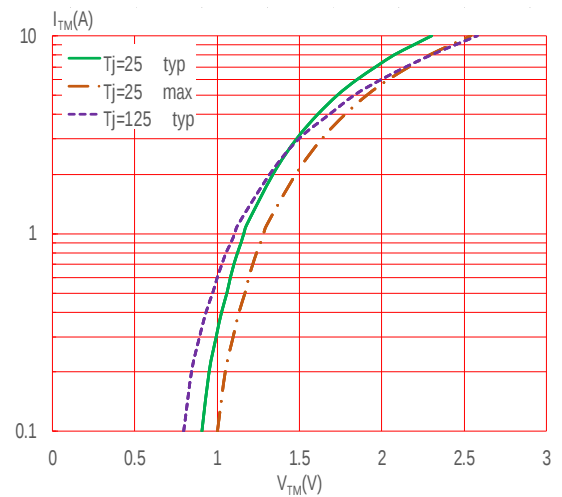
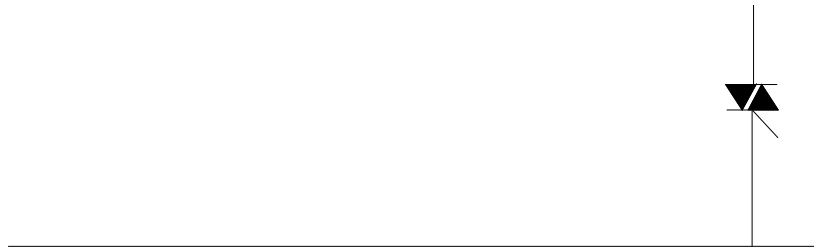
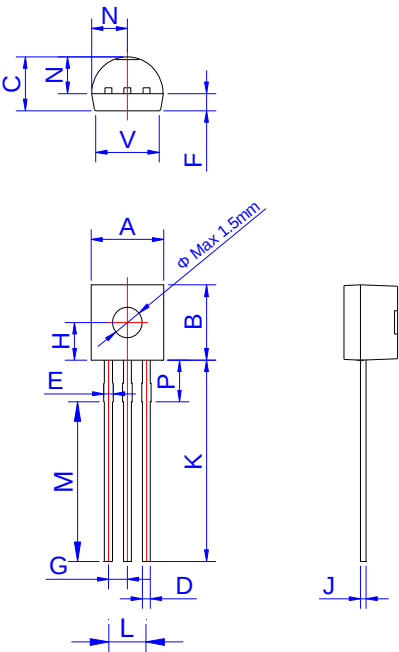
FIG.1: Maximum power dissipation versus RMS on-state current

FIG.3: Surge peak on-state current versus number of cycles

FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 20ms$, and corresponding value of I^2t ($dI/dt < 100A/\mu s$)

FIG.2: RMS on-state current versus case temperature

FIG.4: On-state characteristics

FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature

FIG.7 Test circuit for inductive and resistive loads to IEC-61000-4-5 standards



Order code	Voltage V _{DRM} /V _{RRM} (V)	IGT(mA)	Package	Base qty. (pcs)	Delivery mode
ACJP01U-800SW	800	10	TO-92	1,000	Bulk Pack
ACJP01U-800SW-TR				2,000	Tape & Reel



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.45		5.20	0.175		0.205
B	4.32		5.33	0.170		0.210
C	3.18		4.19	0.125		0.165
D	0.407		0.533	0.016		0.021
E	0.50		0.70	0.020		0.028
F	1.10		1.30	0.043		0.051
G	1.10		1.40	0.043		0.055
H	2.20		2.40	0.087		0.094
J	0.36		0.50	0.014		0.020
K	12.70		15.0	0.500		0.591
L	2.44		2.64	0.096		0.104
M	11.64		12.04	0.458		
N	2.04		2.66	0.080		0.105
P	1.80		2.30	0.071		0.091
V	4.10		4.50	0.161		0.177

PACKAGE

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